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Seat No.				Set	Ρ
М.	Sc.	(Se	emester - I) (New) (NEP CBCS) Examination: Oc PHYSICS (SOLID STATE PHYSICS) Mathematical Physics (2307101)	t/Nov-2023	•
	Day & Date: Friday, 05-01-2024 Max. Marks: 60 Time: 03:00 PM To 05:30 PM Max. Marks: 60				
Instru	ictic		 All questions are compulsory. Figures to the right indicate full marks. 		
Q.1	A)	Chc 1)	The value of $\int_{-\pi}^{\pi} \cos(mx) \sin(nx) dx =$ a) 1 b) $a-1$		08
			a) 1 b) $a-1$ c) 0 d) π		
		2)	If $ z^2 - 1 = z^2 + 1$ then z lies ona) the real axisb) the imaginary axisc) a circled) on ellipse		
		3)	A point at which a function $f(z)$ is not analytic is known as or singularity of the function.a)Scalar pointb)Singular pointc)Non-singulard)None of these	sa	
		4)	Find the pole of $f(z) = \sin \frac{1}{(z-a)} = \underline{\qquad}$.		
			a) $z = a$ b) $z = 0$ c) $z = 1$ d) $z = 4$		
		5)	Laplace transform of $f(t)$ is defined fora) $+ve$ value of t b) $-ve$ value of t c) both $+ve$ & $-ve$ value of t d) None of these		
		6)	Legendre polynomial is a set of function.a) orthogonalb) oddc) evend) real		
		7)	If $f(z) = e^{2z}$ then the imaginary part of $f(z)$ is a) $e^{y} \sin x$ b) $e^{x} \cos y$ c) $e^{2x} \cos 2y$ d) $e^{2x} \sin 2y$		
		8)	What are the eigen values of $\begin{pmatrix} 1 & -i \\ i & 1 \end{pmatrix}$?		
			a) Both are 0 b) 0 and 1 c) 0 and -1 d) 0 and 2		
	B)	Fill 1) 2) 3) 4)	in the blanks OR write true/false. Fourier transform is a linear operator. (True/ False) Inverse of unitary matrix is unitary matrix. (True/ False) A square matrix is called orthogonal if $A = A^{-1}$. (True/ False) $x \frac{\partial u}{\partial x} + t \frac{\partial u}{\partial t} = 2u$ is on ordinary differential equation. (True/		04

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Q.2 Answer the following. (Any Six)

- Find the pole $f(z) = \sin\left(\frac{1}{z-z}\right)$ a)
- What are the conditions for a matrix to be orthogonal matrix? b)
- Solve $\frac{d^2y}{dx^2} 6\frac{dy}{dx} = 9y = 0$ C)
- Find the Laplace transform of the function d)

$$f(t) = te^{-t}\sin 2t$$

Find the pole of $f(z) = \frac{\sin(z-a)}{(z-a)^4}$ e)

Show that inverse of an orthogonal matrix is orthogonal. f)

g) Solve
$$\frac{d^2y}{dx^2} - 5\frac{dy}{dx} + 6y = 0$$

Define singular point, explain in details its types with example. h)

Q.3 Answer the following. (Any Three)

- Discuss in details Cauchy's Integral Formula. a)
- State and prove the Parseval's Theorem. b)
- Show that the eigen value of Hermitian matrix are real. C)
- Find the Fourier Transform of e^{-ax^2} where a > 0d)

Q.4 Answer the following. (Any Two)

Write matrix A gives below as the sum of symmetric & a skew symmetric a) matrix.

$$A = \begin{pmatrix} 1 & 2 & 4 \\ -2 & 5 & 3 \\ -1 & 6 & 3 \end{pmatrix}$$

- b) In square wave expand the function $f(x) = 0; -\pi \le x \le 0$ $f(x) = h; 0 \le x \le \pi$ fourier
- Evaluate the following integral using residue Theorem. C) $\int_{C} \frac{1+z}{z(2-z)} dz$ where c is circle |z| = 1

Q.5 Answer the following. (Any Two) a) Evaluate $\int_0^\infty \frac{\cos 3\theta}{5+4\cos \theta} d\theta$

- **b)** Solve; $x \frac{dy}{dx} + y \log y = xy e^x$
- Solve the differential equation. C)

 $y \log y \, dx + (x - \log y) dy = 0$

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.00	. (00	PHYSICS (SOLID STATE PHYSICS) Solid State Physics (2307102)
		nday, 07-01-2024 Max. Marks: 60 1 To 05:30 PM
ctic) All questions are compulsory. 2) The figure to right indicate full marks.
A)	Cho 1)	ose the correct alternative.08Conductivity of metals depends upona) The nature of the materialb) Number of free electronsc) Resistance of the metald) Number of electrons
	2)	At what temperature does ferromagnetic material become paramagnetic? a) Melting b) Curie c) Neel d) None of these
	3)	Which of the following is a strong magnet? a) Diamagnetic material b) Paramagnetic material c) Antiferromagnetic material d) Ferromagnetic material
	4)	Electronic polarization also known as a) molecular polarization b) magnetic polarization c) atomic polarization d) orientation polarization
	5)	What is the phenomenon where a material exhibits zero electrical resistance below a certain critical temperature? a) Superconductivity b) Conductivity c) Resistance d) Insulation
	6)	 For which of the following is magnetic susceptibility negative? a) Paramagnetic Materials only b) Ferromagnetic Materials only c) Diamagnetic Materials d) none of the above
	7)	 The sprinkling of water reduces slightly the temperature of a closed room because a) Water is a bad conductor of heat b) Water has a large lantern heat of vaporization c) The temperature of the water is less than the room

- d) None of the above
- Which of the following is a property of a superconductor? 8)
 - Perfect diamagnetism a) Low electrical conductivity c)
- High electrical resistance b) Non-zero resistivity d)

Set Ρ M.Sc. (Semester - I) (New) (NEP CBCS) Examination: Oct/Nov-2023

Day & D Time: 0

Seat

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Q.1 A

	B)	 Fill in the blanks OR write true / false. 1) The SI unit of magnetic field intensity is 2) The magnetization 'M' of a superconductor in a field is 3) When a paramagnetic material is heated above Curie temperature it becomes non-magnetic. 4) The temperature above which an antiferromagnetic material becomes paramagnetic is called the melting temperature. 	04
Q.2	Ans a) b) c) d) e) f) g) h)	wer the following. (Any Six). What is Curie Temperature? Define diamagnetic materials. Define specific heat. What is orientational polarization? What is an extrinsic semiconductor? What is penetration depth? State the concept of ferroelectricity. Define Neel temperature.	12
Q.3	Ans a) b) c) d)	wer the following (Any Three) Explain in Brillouin zones in 2-D. Write about the direct and indirect band gap of semiconductors. Explain Meissner's effect. Write a note on the conductivity of solids.	12
Q.4	Ans a) b) c)	wer the following (Any Two) Electronic polarization Explain the Kronig-Penny model. Explain the thermodynamics of superconductors.	12
Q.5	a)	wer the following (Any Two) Write the difference between metal, semiconductors and insulators. Write a note on Josephson's tuppelling and its theory.	12

b) Write a note on Josephson's tunnelling and its theory.c) Explain the Clausius-Mossotti equation

Seat No.		Set P
Μ	I.Sc. (Semester - I) (New) (NEP CBCS) Examination: Oct/Nov-2023 PHYSICS (SOLID STATE PHYSICS) Analog and Digital Electronics (2307106)
		Tuesday, 09-01-2024 Max. Marks: 60 M To 05:30 PM
Instruc	ctions:	 All Questions are compulsory. Figure to right indicate full marks.
Q.1 A	A) Ch 1)	oose correct alternative. (MCQ)08The feedback path in an op-amp integrator consists ofa)a)A resistorb)A capacitorc)A resistor and capacitor in seriesd)A resistor and capacitor in parallel
	2)	Multiplexer has a) Many input and one output b) One input many output c) Many input and many out put d) One input and one output
	3)	Op- amp is a type of amplifier. a) Current b) Voltage c) Power d) Resistance
	4)	The op-amp comparator circuit uses a) Positive feedback b) Negative feedback c) Regenerative feedback d) No feedback
	5)	Find the output of inverting amplifier? a) $V_o = AV_{in}$ b) $V_o = -AV_{in}$ c) $V_o = -A(V_{in1}-V_{in2})$ d) None of the mentioned
	6)	 What happen if any positive input signal is applied to open-loop configuration? a) Output reaches saturation level b) Output voltage swing's peak to peak c) Output will be a sine waveform d) Output will be a non-sinusoidal waveform
	7)	In 8085 microprocessor, how many interrupts are maskable a) Two b) Three c) Four d) Five
	8)	In how many different modes a universal shift register operates a) 2 b) 3 c) 4 d) 5
E	B) Fil 1) 2) 3) 4)	I in the blanks OR Write True /False. 04 The data in stack is called 04 Circuit is used as signal source in all sort of application. 04 bit program counter is available in 8085. 04 The voltage gain of a voltage buffer is 04

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- **b)** Draw AND gate with truth table. c) What is the function of IO/M signal in the 8085? d) What is differential amplifier. e) What is dynamic shift register. f) Why op-amp called direct coupled high differential circuit. g) What is microprocessor? Give the power supply & clock frequency of 8085. **h)** Define CMRR frequency response. 12 Q.3 Answer the following. (Any Three) a) Explain the timing diagram of 8085. b) Explain Multiplexers and Demultiplexers. c) Write a note on RS flip flop and JK flip flop. d) Explain Inverting and Non inverting amplifier. 12 Q.4 Answer the following. (Any Two) a) Define Oscillators? Explain their types. b) Write a note on 8085 instruction set. c) Explain in details of instrumentation amplifier. Q.5 Answer the following. (Any Two) a) Discuss Synchronous and Asynchronous counter.
 - **b)** Draw and explain 8:1 Multiplexers.
 - c) What is multivibrator? Explain the difference between the three types of multivibrators.

- Q.2 Answer the following. (Any Six)
 - a) Define Input offset voltage.

Seat No.

M.Sc. (Semester - I) (New) (NEP CBCS) Examination: Oct/Nov-2023 PHYSICS (SOLID STATE PHYSICS) **Research Methodology in Physics (2307105)**

Day & Date: Thursday, 11-01-2024 Time: 03:00 PM To 05:30 PM

Instructions: 1) All questions are compulsory.

2) Figure to right indicate full marks.

Q.1 A) Choose the correct alternatives from the options.

- 1) A researcher is generally expected to
 - a) Study of existing literature in afield
 - b) Generate new principle and theories
 - c) Synthesis the ideas given by others
 - d) Evaluate the finding of a study

2) Oxides and Nitrides can be applied by _____ evaporation.

- a) E-beam b) Thermal
- c) Magnetron d) DC

Tuning of the refractive index with the density of the films is possible 3) by sputtering.

- a) Magnetron b) DC
- d) RF c) lon beam

The main problem in questionnaire is . 4)

- a) Accessible to Diverse Respondent
- b) Greater Anonymity
- c) Shows an inability of respondent to provide information
- d) None of these
- 5) UV-Vis spectroscopy cannot analyze compounds that with light.
 - a) don't interact b) interact c) merge
 - d) none of the above
- Technique that allow several members of a hiring company to 6) interview a job candidate at the same time is a) Panel Interview
 - b) Self-administered interview
 - c) Mail Interview d) Electronic Interview
- 7) The most common scales used in research are .
 - a) Nominal b) Ratio d) All of the above
 - c) Ordinal
- 8) By selecting laser operating conditions, control over microstructure is
 - a) possible
- b) impossible
- c) not defined d) both a) and b)

Max. Marks: 60

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		 In E-beam evaporation, only the target is heated and not the crucible. (True/False) 	
		 In thermal evaporation, films in the thickness range of angstroms to microns are obtained. (True/False) 	
		 Applied research is conducted to solve practical problems. (True/False) 	
		 The basic research is also called as fundamental research. (True/False) 	
Q.2	Ans a)	swer the following. (Any Six) State the various sampling methods.	12
	b)	Write the applications of Pulsed Laser Deposition.	
	c)	What are the applications of UV-Vis Spectroscopy?	
	d)	What are patents?	
	e)	Define Quantitative research method.	
	f)	Define physical and chemical vapour deposition.	
	g) h)	Write primary literature review sources. What are the applications of FTIR Spectroscopy.	
	,	what are the applications of 1 Th Opechoscopy.	
Q.3	Ans	swer the following. (Any three)	12
	a)	Write a note on Descriptive Vs Analytical research methods.	
	b)	Differentiate between SEM and TEM techniques.	
	,	Write a note on web as source.	
	d)	Write the basic mechanism of sputtering technique.	
Q.4	Ans	swer the following. (Any two)	12
	a)	Define Research? What are characteristics of Research.	
	b)	Discuss different type of Research.	
	C)	Write a note on Review of Literature.	
Q.5	Ans	swer the following. (Any two)	12
	a)	What is Research Design? What are its essentials	
	b)	Write in detail about the concept of Chemical Bath Deposition.	
	c)	Explain in detail about Spray Pyrolysis.	

B) Fill in the blanks OR Write True or False:

Seat No.		Se	et P
	.Sc.	(Semester - I) (Old) (CBCS) Examination: Oct/Nov-2023 PHYSICS (SOLID STATE PHYSICS) Mathematical Physics (MSC10101)	
		riday, 05-01-2024 Max. Ma M To 06:00 PM	rks: 80
Instructi		1) All questions are compulsory. 2) Figures to the right indicate full marks.	
Q.1 A)	Chc 1)	ose correct alternative. The product of a singular matrix with its adjoint is a) a unit matrix b) a null matrix c) an orthogonal matrix d) Square matrix	10
	2)	What is the value of a_0 in the Fourier series of t^2 in the interval $-\pi < t < \pi$? a) 0 b) $\pi^2/_3$ c) $\pi^2/_8$ d) $\pi^2/_4$	
	3)	If A and B are orthogonal matrices, then the product AB is a) symmetric b) antisymmetric c) orthogonal d) unitary	
	4)	Evaluate the integral $\int_{0}^{2\pi} \frac{\sin^{2}\theta}{5 + 4\cos\theta} d\theta$ a) 2π b) π c) $\frac{\pi}{2}$ d) $\frac{\pi}{4}$	
	5)	The value of $\int_{-\pi}^{\pi} \cos(mx) \sin(nx) dx =$ a) 1 b) -1 c) 0 d) π	
	6)	If $ z^2 - 1 = z^2 + 1$ then z lies ona) the real axisb) the imaginary axisc) a circled) on ellipse	
	7)	Find the pole of $f(z) = \sin \frac{1}{(z-a)} = $ a) $z = a$ b) $z = 0$ c) $z = 1$ d) $z = 4$	
	8)	In Cauchy's Residues theorem $\oint_{\Gamma} f(z) dz = $ a) $2\pi i \sum_{j=1}^{n} a_{-1} zj$ b) $2\pi i$ c) $2\pi i \sum_{j=1}^{n} a_{+1} zj$ d) $2\pi i \sum_{j=1}^{n}$	

9) _____ is the real part (Re Z) & _____ is the imaginary (Im Z), of the given z = (1 + i)/(2 - 3i).

a) $-\frac{1}{13} \& \frac{5}{13}$	b)	$-\frac{1}{11}$ & $\frac{4}{13}$
C) $\frac{1}{3} \& -\frac{5}{13}$	d)	$\frac{1}{09}$ & $\frac{5}{13}$

10) Legendre polynomial is a set of _____ function. a) orthogonal b) odd

c) even d) real

B) Fill in the blanks OR write true/false.

- a) A necessary and sufficient condition that solution y_1 and y_2 of y'' + p(x)y' + q(x)y = 0 is linearly independent is that the Wronskian is zero. (True/False)
- b) Fourier series can be used to represent discontinuous where all orders of derivatives need not exist. (True/False)
- c) The Fourier transform operator is unitary.
- d) The first order ODE can never be linear separable and exact at the same time. (True/False)
- e) A Fourier transform is a linear operator. (True/False)
- f) A square matrix is called orthogonal if $A = A^{-1}$. (True/False)

Q.2 Answer the following.

- a) If A and B are two orthogonal matrices, show that AB is also orthogonal matrix.
- **b)** Find the Laplace transform of $\frac{s^2 a^2}{(s^2 + a^2)^2}$

c) Find the residue of
$$\frac{1}{(z^2+1)^3}$$
 at $z = i$
d) Solve $y e^y dx = (y^3 + 2xe^y)dy$

Q.3 Answer the following.

a) Solve $x \frac{dy}{dx} + y \log y = xye^x$ b) Find the eigen value of a matrix $\begin{bmatrix} 2 & 1 & 1 \\ 1 & 2 & 1 \\ 0 & 0 & 1 \end{bmatrix}$ 08

Q.4 Answer the following.

a)

Determine the value of α, β, r when $\begin{bmatrix} 0 & 2\beta & r \\ \alpha & \beta & -r \\ \alpha & -\beta & r \end{bmatrix}$ is orthogonal.

b) Determine the poles of the function z, $f(z) = \frac{1}{z^4 + 1}$ **08**

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Q.5 Answer the following.

Q.6

Q.7

)	_	swer the following.	•••
	a)	Solve $\sin x \frac{dy}{dx} + 2y = \tan^3\left(\frac{x}{2}\right)$	08
	b)	Verify Cayley - Hamilton Theorem for the following matrix.	08
		$\begin{bmatrix} 2 & -1 & 1 \\ -1 & 2 \end{bmatrix}$ and use the theorem to find 4^{-1}	
		$A = \begin{bmatrix} 2 & -1 & 1 \\ -1 & 2 & -1 \\ 1 & -1 & 2 \end{bmatrix}$ and use the theorem to find A^{-1}	
5	Ans	swer the following.	
	a)	Find the order of each pole and residue of $\frac{1-2z}{z(z-1)(z-2)}$	80
	b)	Show that the eigen value of Hermitian matrix are real.	08
,	Ans	swer the following.	
	a)	In square wave expand the function.	08
	,	$f(x) = 0; -\pi \le x \le 0$	
		$f(x) = 4; -0 \le x \le \pi$ Fourier.	
	b)	Explain Laplace transform of Derivatives.	08

Seat No.		Set I	Ρ
	M.Sc.	Semester - I) (Old) (CBCS) Examination: Oct/Nov-2023 PHYSICS (SOLID STATE PHYSICS) Solid State Physics (MSC10102)	
		nday, 07-01-2024 Max. Marks: 8 To 06:00 PM	30
Instru	2	Q. Nos. 1 and. 2 are compulsory. Attempt any three questions from Q. No. 3 to Q. No. 7 Figure to right indicate full marks.	
Q.1	A) Cho 1)	Dse the correct alternative.The correct alternative.The correct alternative.Effective mass is equal to mass for free electron.a)Meana)Meanb)realc)Residuald)zero	10
	2)	Elemental solid dielectric has only polarization.a) Electronicb) ionicc) orientationald) all	
	3)	 In the case of p-type semiconductors, the Fermi level lies at a) Below near to conductor band b) Above near to valence band c) Below near to valence band d) At the middle of the valence and conduction band 	
	4)	In the case of superconductor, at Tc conductance becomesa) Zerob) Finitec) Infinited) None of the above	
	5)	has a positive temperature coefficient of resistance.a)Metalb)Semiconductorc)Insulatord)Dielectric	
	6)	The coordination number of HCP isa) Twob) Fourc) Sixd) Twelve	
	7)	Plane cut to negative x-axis have the miller indicesa)(011)b)(001)c)(110)d)(-100)	
	8)	The zone lies in between $+\pi/2$ to $-\pi/2$ is the Brillion zone. a) 1 st b) 2 nd c) 3rd d) 0 th	
	9)	Relative permittivity (ε_r) of the air is a) 2 b) 0.5 c) 1 d) 0	
	10)	Intrinsic concentration of charge carriers in a semiconductor varies as $\overrightarrow{a)}$ \overrightarrow{T} \overrightarrow{b} $\overrightarrow{T^2}$ \overrightarrow{c} $\overrightarrow{T^3}$ \overrightarrow{d} $1/T$	

	B)	 Fill in the blanks OR Write True or False Some conductors are below critical temperature. FCC structure contains the contribution of atoms. The packing fraction of the BCC structure is 74%. (T/F) NaCl shows orientation polarization. (T/F) Diamond is a conductor. (T/F) The addition of pentavalent impurity creates an n-type semiconductor. (T/F) 	06
Q.2	a) b) c)	wer the following (any four) Write about orientational polarization. Explain Meissner's effect. Derive the rectifier equation Show that in the case of an intrinsic semiconductor $E_f = (E_c + E_v)/2$ Write a note on dielectric Breakdown.	16
Q.3		wer the following	
	a)	What is meant by imperfections in crystals? Explain the various defects in the crystal.	10
	b)		06
Q.4	Ans [.] a) b)		10 06
Q.5	Ans	wer the following	
	a) b)		80 08
Q.6	Ans a) b)	I	10 06
Q.7	Ans [.] a) b)		10 06

Seat No.			Set	Ρ
	M.Sc.	(Semester - I) (Old) (CBCS) Examination: Oct/Nov-20 PHYSICS (SOLID STATE PHYSICS) Analog and Digital Electronics (MSC10103)	23	
			. Marks	: 80
Instructi	2) All questions are compulsory. 2) Attempt any three questions from Q.3 to Q.7. 3) Figure to right indicate full marks.		
Q.1 A)	Cho (1)	 bose correct alternative. (MCQ) The basic SR flip-flop can be constructed by cross coupling by us which of the gates? a) AND or OR gate b) XOR or XNOR gate c) NOR or NAND gate d) AND or NOR gate 	sing	10
	2)	In JK flip-flop "no change" condition appear when a) $J = 1, K = 1$ b) $J = 0, K = 0$ c) $J = 1, K = 0$ d) $J = 0, K = 1$		
	3)	Which is the 16-bit register for 8085 microprocessor? a) Stack pointer b) Accumulator c) Register B d) Register C		
	4)	 The feedback path in an op-amp integrator consists of a) A resistor b) A capacitor c) A resistor and capacitor in series d) A resistor and capacitor in parallel 		
	5)	Multiplexer has a) Many input and one output b) One input many output c) Many input and many out put d) One input and one output		
	6)	 The op-amp comparator circuit uses a) Positive feedback b) Negative feedback c) Regenerative feedback d) No feedback 		
	7)	Op- amp is a type of amplifier a) Current b) Voltage c) Power d) Resistance		
	8)	An XOR gate can be used for a) Inverter and non-inverter b) Only inverter c) Only non-inverter d) None of the above		

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9)	Which of the following addressing method does the instruction,
	MOV AX,[BX] represent?

- a) register indirect addressing mode
- b) direct addressing mode
- c) register addressing mode
- d) register relative addressing mode
- 10) Which of the following is a property of RST 7.5 interrupt?
 - a) It is a non-maskable interrupt
 - b) It has 3rd highest priority
 - c) It uses level-triggered signal
 - d) Its vectored address is 003C H

B) Fill in the blanks

- 1) In an instrumentation amplifier, the output voltage is based on the _____ times a scale factor.
- 2) The output voltage of a voltage buffer is _____ with the input voltage.
- 3) The voltage gain of a voltage buffer is _____.
- 4) The data in stack is called
- 5) The sequential circuit is also called
- 6) There are _____ general purpose registers in 8085 microprocessor.

Q.2 Answer the following

- a) Define
 - i) Input offset voltage
 - ii) Voltage follower
- b) Draw AND gate and NOT gate with truth table.
- c) What is microprocessor? Give the power supply & clock frequency of 8085 and List the allowed register pairs of 8085.
- d) Write a note on Demorgan's Theorem.

Q.3 Answer the following.

	a) b)	Draw and explain architecture of 8085 microprocessor. Explain Multiplexers and Demultiplexers.	10 06
Q.4	Ans	swer the following.	
	a)	What is multivibrator? Explain the difference between the three types of multivibrators.	10
	b)	Draw and explain 8:1 Multiplexers.	06
Q.5	Ans a) b)	wer the following. Explain the operation of three op-amp instrumentation amplifier. Define Oscillators? Explain their types.	10 06
Q.6	Ans	swer the following.	
	a)	Explain inverting configuration of Op amp as a summing, scaling and averaging Amplifier.	10
	b)	Explain Inverting and Non inverting amplifier.	06
Q.7	Ans	swer the following.	
	a) b)	Explain the instruction set of 8085 microprocessor. Draw and explain memory read cycle of 8085 microprocessor.	10 06

Seat No.			Set P
NO.	M.Sc.	(Semester - I) (Old) (CBCS) Examination: Oct/No PHYSICS (SOLID STATE PHYSICS) Classical Mechanics (MSC10108)	ov-2023
		ursday, 11-01-2024 / To 06:00 PM	Max. Marks: 80
Instru	2) Q. Nos. 1 and. 2 are compulsory. 2) Attempt any three questions from Q. No. 3 to Q. No. 7 3) Figure to right indicate full marks.	
Q.1	A) Cho 1)	bose correct alternative. The position of a particle at any time t subjected to resistive. a) $x = k \cdot (1 + e^{-kt})/v_o$ b) $x = kv_o(1 - e^{-kt})$ c) $x = v_o(1 - e^{-kt})/k$ d) $x = kv_o(1 + e^{-kt})$	10 re force is
	2)	The rate of momentum change of an open system is equal a) $T + MU$ b) $F - MV$ c) $W - MV$ d) $F + MU$	l to
	3)	The reduced mass of two bodies into equivalent one body a) $(m_1 + m_2)/(m_1 \cdot m_2)$ b) $(m_1 \cdot m_2)/(m_1 - m_2)$ c) $m_2/(1 + m_2/m_1)$ d) $m_1/(1 + m_2/m_1)$	
	4)	The time derivative of generalized co-ordinate isa) Generalized forceb) Generalized velocityc) Generalized momentumd) None of these	/
	5)	 For E > 0 and ε > 1, the nature of the orbit is a) Circle b) Parabola c) Ellipse d) Hyperbola 	
	6)	The generalized momentum is equal toa) $\partial L/\partial q_j$ b) $\partial L/\partial \dot{p}_j$ c) $\partial L/\partial \dot{q}_j$ d) $\partial L/\partial p_j$	
	7)	Which of the following defines a conservative force <i>F</i> ? a) $dF/dt = 0$ b) $\nabla F = 0$ c) $\nabla \times F = 0$ d) $\oint F. dr = 0$	
	8)	Poisson brackets are under canonical transformata) Variantb) nullifiedc) anti-symmetricd) invariant	ion.
	9)	 Generalized coordinated a) are independent of each other b) depend on each other c) are always cartesian coordinates d) are always spherical polar coordinates 	
	10)	The $F_2 = \sum q_k P_k$ transformation defined as a) generates exchange transformation b) generates identity transformation c) is not canonical transformation d) None of the above	

	B)	 Fill in the blanks or write true /false. 1) Scleronomic constraint do not explicitly depends on time. (True/False) 2) q_j's which are absent in <i>L</i> are cyclic coordinates. (True/False) 3) Rutherford's differentia scattering cross section has dimensions of solid angle. (True/False) 4) The Euler-Lagrangian differential equations is 5) Lagrangian is equal to 6) [L_x, L_y] = 	06
Q.2	a)	 swer the following questions. Which conditions are used to verify that the transformation is canonical? Prove any one condition. Prove that forces acting on a particle are conservative then the total energy <i>E</i> of a particle is conserved. Distinguish between the configuration space and phase space. Define Hamiltonian. Give its physical significance. 	16
Q.3	An a) b)	 swer the following. Derive the equation of motion of a particle and deduce the acceleration of Atwood machine under constant force. Obtain the equation of motion of 1) a particle subjected to a resistive force 2) a projectile (no resistance) 	10 06
Q.4	An a) b)	swer the following. Derive the formula for Rutherford scattering cross-section. Derive an equivalent equation for reduction to one body problem from two body problem.	10 06
Q.5	a)	swer the following. State the Kepler's laws of planetary motion and prove the Kepler's third law. Deduce the Lagrange's equation of motion from Hamilton's principle and using derive the generalized momentum.	10 06
Q.6	An a) b)	swer the following. Derive canonical equations of Hamilton. Also write the procedure for constructing Hamiltonian. Obtain Hamilton's equation for one dimensional harmonic oscillator.	10 06
Q.7	An a) b)	swer the following. State and prove Poisson's theorem. Prove the Jacobi identity [<i>V</i> , [<i>V</i> , <i>W</i>]] + [<i>V</i> , [<i>W</i> , <i>U</i>]] + [<i>W</i> , [<i>U</i> , <i>V</i>]] = 0	10 06

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No.	

M.Sc. (Semester - II) (New) (CBCS) Examination: Oct/Nov-2023 PHYSICS (SOLID STATE PHYSICS) Quantum Mechanics (MSC10201)

Day & Date: Monday, 18-12-2023 Time: 11:00 AM To 02:00 PM

Instructions: 1) Q. Nos. 1 and. 2 are compulsory.

3) Figure to right indicate full marks.

Q.1 A) Fill in the blanks by choosing correct alternative.

- 1) If Ψ_a and Ψ_b are said to be orthogonal to each other, then which of the following is true.
 - a) $\langle \Psi_a | \Psi_b \rangle = 1$ b) $\langle \Psi_a | \Psi_b \rangle = \infty$
 - c) $\langle \Psi_a | \Psi_b \rangle = \sqrt{1/2}$ d) $\langle \Psi_a | \Psi_b \rangle = 0$
- 2) If two operators do not commute with each other, then which of following statement is true.
 - a) They do not share common eigenfunction.
 - b) They do share common eigenfunction.
 - c) Their eigenvalues are same.
 - d) They must anti-commute.

3) The minimum energy of particle confined to one dimensional rigid box is obtained by substituting n equal to _____.

- a) one b) zero
- c) half d) two

4) The total energy operator or Hamiltonian operator is given by $H^{\wedge} =$ _____.

a) $\hat{p}^2/2m$ b) V(x) $(\hat{p}^2/2m) + V(x)$ $(\hat{p}^2/2m) - V(x)$ c) d) 5) Energy of harmonic oscillator is, E = $(1/2)\hbar\omega$ nħω a) b) $(n + 1/2)\hbar\omega$ d) $(n - 1/2) \hbar \omega$ C) The eigen value of L^2 is _____. 6) $l(l+1)\hbar^{2}$ b) $l(l-1)\hbar$ a) $l(l^2 + 1)\hbar^2$ $l(l+1)\hbar$ c) d) Which of the following is lowering operator _____. 7) $L_{r} + iL_{v}$ b) $L_x - L_v$ a) $L_{x} - iL_{y}$ c) d) 0 8) The commutation relation between $[x, P_x]$ and $(\partial/\partial x, x]$ is a) *i*ħ, 0 b) 0,*i*ħ $-i\hbar$, 1 d) *i*ħ, 1 c) 9) Which of the following equation is correct?

a) $[\hat{y}, \hat{p}z] = i\hbar$ b) $[\hat{x}, \hat{p}y] = i\hbar$

c) $[\hat{z}, \hat{p}x] = i\hbar$ d) $[\hat{z}, \hat{p}z] = i\hbar$

Max. Marks: 80

²⁾ Attempt any three questions from Q. No. 3 to Q. No. 7

- 10) Which of the following equations is/are correct?
 - i) $K = r \times p$
 - ii) $L = iL_x + jL_y + kL_z$
 - iii) $L^2 = L.L$
 - iv) $L^2 = L_x^2 + L_y^2 + L_z^2$
 - i and ii only a)
 - i, ii and iv are correct c)

iii and iv only are correct b) All are correct d)

B) Fill in the blanks or Write True /False.

- Diffraction and interference are the evidence of wave nature of 1) matter. (True/False)
- 2) Eigen values of Hermitian operator are not real. (True/False)
- 3) Inner product of Bra and Ket in Quantum mechanics is always 1. (True/False)
- 4) For a free particle the potential energy V(x) =_____.
- 5) Potential energy of a particle in harmonic oscillator having mass mis
- The linear momentum operator is given by . 6)

Q.2 Answer the following.

- Normalize the following wave- function in one- dimension: a)
 - $\psi(x) = Ae^{-ax}$ for x > 0
 - $= Ae^{+ax}$ for x < 0

where α is a positive constant.

- Prove that eigen function of Hermitian operator with different eigen values b) are orthogonal to each other.
- Explain unitary transformation. C)
- Define the different postulate of Quantum mechanics. d)

Q.3 Answer the following.

- Derive the time independent Schrödinger equation in 3D. a) 10
- Deduce the continuity equation. b)

Q.4 Answer the following.

a)	Obtain Schrödinger's wave equation for Hydrogen atom in terms of	10
	spherical polar coordinates, express its radial and angular parts.	
b)	Define angular momentum and explain the commutation relation.	06

Q.5 Answer the following.

- What is momentum eigen function in the co-ordinate representation? 10 a) Elaborate. 06
- Write down the co-ordinate and momentum representation. b)

Q.6 Answer the following.

- What is the Clebich Gordon coefficient? Explain the construction procedure. 10 a) With simple examples. 06
- Describe the Pauli spin matrices. b)

Q.7 Answer the following.

- Define square well potential in one dimension. Discuss motion of a particle 10 a) of mass m when energy of the particle is less than potential $(E < V_0)$. 06
- Obtain eigen values of operators L^2 and Lz. b)

06

06

				Electrodynamics (•
Time	Day & Date: Tuesday, 19-12-2023 Time: 11:00 AM To 02:00 PM Instructions: 1) Q. No. 1 and 2 are compulsory. 2) Attempt any Three questions from Q.No.3 to Q.No.7. 3) Figures to the right indicate full marks.					
Q.1	A)	Cho 1)	Div a)	the correct alternatives from ergence of the curl of any vector 0 Infinite	or fie b)	•
		2)	forr a)	ich one of the fundamental equ n the basis of electromagnetic Faraday law Gauss law of electrostatic	theo b)	•
		3)	a)	entz electric force has directior Similar to electric field Scalar quantity	b)	Opposite to electric field
		4)	a)	e Poynting vector P is equal to E . H E/H	b)	 E × H H/E
		5)	me a)	ich property of an electromagn dium in which it is travelling? Velocity Time period	b)	wave, depends on the Frequency Wave length
		6)	am a)	the skin definition of skin dep plitude reduces to Nearly one fifth One half	b)	is distance over which field 1/e One fourth
		7)	a)	Maxwell equation $∇ × H = J + ∂$ Electric flux density Surface current density	b)	magnetic flux density

M.Sc. (Semester - II) (New) (CBCS) Examination: Oct/Nov-2023 PHYSICS (SOLID STATE PHYSICS)

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		8)	Law which governs the interaction of the electromagnetic field with charge matter	
			a) Gauss law b) Faradays law	
			c) Amperes law d) Lorentz force law	
		9)	Magnetic vector potential due to magnetic dipole is proportional to	
			a) r b) $1/r$ c) $1/r^2$ d) $1/r^3$	
		10)	Electric Potential (Φ) of a quadrupole varies with distance 'r' on its axis as	
			a) $\Phi: r^{-1}$ b) $\Phi: r^{-2}$ c) $\Phi: r^{-3}$ d) $\Phi: r^{3/2}$	
	B)	Fill i	n the blanks OR Write Ture /False 0	6
		1) 2) 3) 4)	The charge density of electrostatic field is given by In dipole, the gauss theorem value will be The Ampere law is based on Theorem The electric field over the gaussian surface remains continuous and	
		5) 6)	uniform at every point. In Biot-Savart's law, the magnetic intensity is product of the current. The direction of a propagation of electromagnetic wave is \overline{E} . \overline{B} .	
Q.2			5	6
	a)		ain Maxwell's displacement current?	
			a note on Skin effect and skin depth? ain the concept of Thomson cross section?	
	c) d)		the boundary condition for an electrostatic field \overline{E} .	
Q.3	Ans a)		he following. uss the "Reflection and refraction" of electromagnetic waves at 1	0
	aj		ue incidence.	U
	b)			6
Q.4	Ans a)		he following. ain in details of boundary condition between conductor and free 1	0
	u)	spac	•	Ŭ
	b)	Obta fields	ined the expression for the resistance for uniform field &non-uniform 0 5.	6
Q.5			he following.	
	a) b)		re an expression for energy stored in electric and magnetic field. 10 ain the concept of Radiation damping. 06	

Q.6	Ans a) b)	swer the following. Derive the general expression for electromagnetic energy. Discuss Electromagnetic plane waves in stationary medium?	10 06
Q.7	Ans a) b)	swer the following. Explain the concept of radiation from a half wave antenna. What is Gauss law? Explain differential form of its.	10 06

M.Sc. (Semester - II) (New) (CBCS) Examination: Oct/Nov-2023 PHYSICS (SOLID STATE PHYSICS) Statistical Physics (MSC10206) Max. Marks: 80

Day & Date: Wednesday, 20-12-2023 Time: 11:00 AM To 02:00 PM

Seat

No.

Instructions: 1) Question No.1 and 2 are compulsory.

- 2) Attempt any three questions from Q. No. 3 to Q. No. 7.
- 3) Figure to right indicate full marks.

Q.1 A) Choose the correct alternatives from the options.

- Which law of thermodynamics is the law of conservation of energy? 1)
 - a) First b) Second
 - c) Zero d) Third
- 2) The phase space is _____ dimensional space.
 - a) 3N b) 6N c) N
 - d) 2N

The statistics followed by half spin particles is _____. 3)

- a) Maxwell-Boltzmann Statistics
- b) Fermi-Dirac Statistics
- c) Bose-Einstein Statistics
- d) None of the above

Maxwell-Boltzmann statistics cannot be applied to _____. 4)

- a) Atoms b) Molecules
- c) Photons d) Lattice

The equation of state for an ideal gas is represented as 5)

- a) PV = R/Tb) PV = nRT
- d) PV = RTc) P/V = R/T

6) The entropy of an ideal gas at absolute zero is

- a) ∞ b) 0 c) NkB
 - d) Cannot be calculated

For which gas mutual interaction between the molecules is zero. 7)

- a) real Fermi b) c) Ideal d) Bose
- Total heat of the substance is also known as _____. 8)
 - a) Internal energy b) Entropy
 - c) Thermal Capacity d) Enthalpy

Pressure at the critical point is 9)

a) 3b b) 8/27R d) c) 3b/27Rb8a/27Rb

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10) In microcanonical ensembles following parameters remain constant.

			• •
a)	TVN	b)	EVN

c) EVT d) $EV\mu$

B) Fill in the blanks OR write true/ false.

- 1) The ratio of the universal gas constant and Avogadro's number is called the velocity constant.
- 2) The transition in β -brass is an example of a second-order phase transition.
- 3) Photon, Phonon, etc. obeys the Fermi Dirac distribution function.
- 4) Entropy in thermodynamics is a measure of the disorder of the system.
- 5) The value of the universal gas constant is 8.3143
- 6) A phase space is a six-dimensional space.

Q.2 Answer the following.

16

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- a) State the types of ensembles and point out the difference between canonical and Grand Canonical Ensemble.
- b) Discuss the conditions for phase equilibrium.
- **c)** Show that during the second order phase transition $\partial^2 G_1 / \partial T^2 \neq \partial^2 G_2 / \partial T^2$.
- d) What is a partition function? Derive it for Canonical Ensemble.
- e) Explain the P-T diagram of the phase transaction.

Q.3 Answer the following.

G.U			
	a)	Show that Gibb's function is continuous during the first-order phase transition, but the first derivative of Gibb's function changes discontinuously.	10
	b)	What is a triple point? Explain it with the help of a phase diagram.	06
Q.4	Ans	wer the following.	
	a)	Write a note on Critical Indices	10
	b)	Write about Liouville's theorem in a classical presentation.	06
Q.5	Ans	wer the following.	
	a)	Write about Second order phase transition.	08
	b)	Write a note on microcanonical, canonical and grand canonical ensembles.	08
Q.6	Ans	wer the following.	
	a)	Show that the average energy of a single particle of ideal fermi gas is 3/5 times the fermi energy of the system.	10
	b)	Explain the law of corresponding states.	06
Q.7	Ans	wer the following.	
	a)	Derive the expression for Fermi energy at strongly degenerate ideal	10
	,	Fermi gas.	
	b)	Write about black body radiation.	06

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M.Sc. (Semester - III) (New) (CBCS) Examination: Oct/Nov-2023
PHYSICS (SOLID STATE PHYSICS
Semiconductor Physics (MSC10301)

Day & Date: Friday, 05-01-2024

Time: 11:00 AM To 02:00 PM

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Instructions: 1) Q. No. 1 & 2 are compulsory.

- 2) Attempt any three questions from Q. 3 to 7.
- 3) Figures to the right indicate full marks.

Q.1 A) Choose correct alternatives.

- 1) When a piece of pure silicon is doped with indium, then____
 - a) The doped silicon piece will become n-type semiconductor
 - b) The doped silicon piece will become p-type semiconductor
 - c) The conductivity of the doped silicon piece will remain the same
 - d) The resistivity of the doped silicon piece will increase
- 2) Compound semiconductors such as GaAs have_____.
 - a) ionic bonding
 - b) metallic bonding
 - c) covalent bonding
 - d) mixed bonding, in which both ionic and covalent bonding forces participate.
- 3) Which of the following semiconductor has indirect band gap?
 - a) Ge and GaAs
- b) Si and GaAsd) Ge and Si
- c) GaAs d
- 4) In direct electron transition _____.
 - a) there is no change in momentum of electron
 - b) there is no change in momentum of electron
 - c) there is change in propagation vector, k of the electron
 - d) electron jumps from an impurity level to the conduction band
- 5) An intrinsic semiconductor at absolute zero temperature (0 K) has _____.
 - a) an empty valence band and an empty conduction band
 - b) a filled valence band and filled conduction band
 - c) a filled valence band and an empty conduction band
 - d) an empty valence band an a filled conduction band
- 6) _____ is the initial process that occurs in the formation of a crystal.
 - a) Growth

c)

- b) Nucleation
- atomic bonding d) Clusters

Max. Marks: 80

- 7) _____ is the series of process by which an atom or molecule is incorporated into the surface of crystal.
 - a) crystal growth c) Clusters
- b) Nucleation d) atomic bonding

b)

d)

- 8) Epitaxial techniques have been used for the growth of epilayers of III-V, II-VI compound_____ and other materials.
 - a) metals c) semiconductors
- b) insulators d) plasma
- 9) Czochralski method is crystal growth of _
 - a) growth from melt
 - c) growth from solution
- 10) The driving force needed for the nucleation and growth of crystal is referred as
 - a) nucleation force
- b) supersaturationd) molecular force

growth from vapor

growth from solid

c) growth force d) n

Q.1 B) Fill in the blanks OR write True /False

- 1) In a semiconductor, most holes occupy states near the bottom of the valence band.
- 2) A semiconductor with band gap of about 2 eV wide, allows only long wavelengths (infrared) and the red part of the visible spectrum to transmit through it.
- 3) Electrons are distinguishable and obey Pauli Exclusion Principle.
- 4) First step in crystal growth is transport of atoms through solution.
- 5) Epitaxy means growth of many crystal films on top of a crystalline substrate.
- 6) Molecular beam epitaxy is a process of depositing epitaxial thin films from molecules or atomic beams on a heated substrate under UHV conditions.

Q.2 Answer the following.

- a) Discuss random thermal velocity and drift velocity of charge carriers in a semiconductor.
- **b)** Distinguish between direct and indirect band gap semiconductors.
- c) What is nucleation rate and induction time?
- d) Write advantages of epitaxial techniques.

Q.3 Answer the following.

- a) Discuss electrical conductivity and mobility in a semiconductor.
- **b)** What is principle of vapor phase epitaxy? Explain with neat diagram vapor phase epitaxy.

Q.4 Answer the following.

- a) Discuss bonding forces in solids.
- **b)** What is liquid phase Epitaxy? Explain with neat diagram the liquid phase epitaxy.

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Q.5 Answer the following.

- a) Discuss in detail "Effective mass" of an electron in a band.
- **b)** Explain the theory of nucleation and growth.

Q.6 Answer the following.

- a) Discuss diffusion process of charge carriers in a semiconductor.
- b) With neat diagram, discuss zone melting method of crystal growth with advantages.

Q.7 Answer the following.

- a) Discuss in detail "The Haynes-Shockley Experiment."
- b) With neat diagram, discuss Czochralski method of crystal growth. Mention advantages and disadvantages of the method.

16

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M.Sc. (Semester - III) (New) (CBCS) Examination: Oct/Nov-2023 PHYSICS (SOLID STATE PHYSICS) Atomic and Molecular Physics (MSC10302)

Day & Date: Sunday, 07-01-2024 Time: 11:00 AM To 02:00 PM

Max. Marks: 80

10

Instructions: 1) Question no. 1 and 2 are compulsory.

- 2) Attempt any three questions from Q. No. 3 to Q. No. 7.
- 3) Figure to right indicate full marks.

Q.1 A) Multiple choice questions.

- 1) In computing the splitting of spectral lines in a weak magnetic field the lande g-factor arises because of _____.
 - a) Pauli Exclusion Principle b) spin-orbit coupling
 - c) larmor precession d) relativistic correction
- 2) Laser cooling of atoms is produced due to _____.
 - a) Absorption of photons by atoms
 - b) scattering of photons by atoms
 - c) Transfer of momentum from photon to atoms
 - d) transfer of energy from photons to atoms.
- First raman shifted line observed at 218 Cm-1 for CCl4 excited by 632.8nm of HE-Ne laser, will correspond to scattered wavelength at (given h=6.6*10⁻³⁴Js C=3*10⁸m)
 - a) 128.5nm b) 621.8nm
 - c) 5000.0nm d) 641.6 nm
- 4) The outermost shell of an atom of an element is 3d3. The spectral symbol for the ground state

a) ⁴ F _{3/2}	b)	⁴ F9/2
c) ⁴ D _{7/2}	d)	⁴ D _{1/2}

- 5) A negative muon, which has a mass nearly 200 times that of an electron, replaces an electron in a Li atom. The lowest ionization
 - energy for the muonic LI atom is approximately.
 - a) The same as that of He
 - b) The same as that of normal LI
 - c) The same as that of normal Be
 - d) 200 time larger than that of normal LI
- 6) Which of the following molecules does not exibit a rotational spectrum.
 - a) HCI b) CO
 - c) H2 d) HBr
- 7) JJ coupling is the _____ Coupling.
 - a) Weak b) strong
 - c) less weak d) none of these
- 8) One electron in P orbit and a other in a D orbit, in case of II coupling, the atom may be in a _____ state.
 - a) SPD b) PDF
 - c) DFG d) Only D

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- 9) Which of the following molecule will not show the microwave spectra.
 - a) CH_2CI_2 b) SF_6
 - c) H₂O d) CH₃CI
- 10) The lowest vibrational energy is given by _____.
 - a) ½ ω b) ω
 - c) $\frac{1}{2}\omega^2$ d) ω^2

B) Fill in the blanks or True false from give parenthesis

- 1) _____ Detector is an IR detector (crystal / Pyroelectric)
- 2) At J=0 i.e ground rotational state, in which the _____ (rotation / no rotation)
- Intensity rule for the Zeeman effect of the atomic systems containing more than one valance electron is _____ of type of coupling (dependent /Independent)
- 4) When L is greater than or equal to S, all integral Value of J between L-S and L+S are allowed.
- 5) Hyperfine structures arises in tungsten due to presence there even isotopes tungsten.
- 6) The spherical top molecule have dipole moment owing to their symmetry.

Q.2 Answer the following.

- a) Give selection rule for LS and JJ coupling
- **b)** State and explain the intensity rule for Zeeman Effect.
- c) Distinguish between normal and anomalous Zeeman Effect.
- d) Find the spectroscopic term for npl,np2,np4,np5.

Q.3 Answer the following.

- a) With the schematic diagram, write the construction and working of stern
 12 gerlach experiment.
- b) The spin orbit coupling constant for the upper state of Na atom which emits
 D lines for weak numbers 16959cm-1 and 1697.4cm-1 is?

Q.4 Answer the following.

- a) What are the assumption made for the deriving an expression for Lande 'g' factor? Obtain the expression for the Lande 'g' factor for LS coupling.
- b) In a hydrogen atom the accidental or coulomb degeneracy for the n=4 state 04 is? {111}.

Q.5 Answer the following.

- a) Write the consequences for bond elasticity for diatomic molecule as a nonrigid rotator.
- b) The number of Zeeman component for 2D3/2 --> 2P3/2 transition in one 04 electron atom will be?{124}

Q.6 Answer the following.

- a) Discuss the techniques and instrumentation of microwave spectrometer and 12 its use in chemical analysis
- **b)** The land's g factor for the ${}^{3}P_{1}$ level of an atom is? {91}.

Q.7 Answer the following.

- a) Draw the vibrational energy levels and some transition between them for a diatomic molecules undergoing anharmonic oscillations
- b) Consider a state in which I=4, s=1/2 the orientation of total angular moment
 04 w.r.t Cos 45 the state with largest possible J, mj is? {55}

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	М.\$	-	PH	- III) (New) (CBCS) YSICS (SOLID STA Ital Techniques for	TE P	•
		e: Tue	esday, 09-0 To 02:00 P	1-2024	,	Max. Marks: 80
Instru	uctio	2)	Attempt an	and. 2 are compulsory. y three questions from (ght indicate full marks.	ຊ. No	o. 3 to Q. No. 7
Q.1	A)	Cho	ose correct	alternatives.		10
Q. 1	<i>Α</i> j	1)	Dielectrics a) Pyroe		b)	larization are called as Piezoelectric Centrosymmetric
		2)	a) Decre	pressure.	bress b) d)	ures, the thermal conductivity increases first decreases then increases
		3)	Resolution a) 1 mm c) 1 nm	of SEM is approximatel	y b) d)	 1 μm 1 cm
		4)	a) Geige	generated by er tube dge tube	b) d)	Goniometer Rotameter
		5)	The CMRF a) 50dB c) 240dB	R of an in-amp will be arc 3	bund b) d)	50dB 120dB
		6)		ing power of TEM is der ons r		
		7)		ignal is called a ducer	duai b) d)	ntity into the proportional sensor none of these
		8)	a) Electr	temperature. ical conductivity	b)	echnique is used to measure mass specific heat
		9)	a) Miche b) a com c) a lase	•		

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		 10) LED is a PN junction diode under biased. a) forward b) reversed c) both forward as well as reverse d) not any 	
	B)	 Fill in the blanks OR write true/ false. 1) In SEM, convex lens is used for focussing electrons. 2) In electromagnetic spectrum, the infrared region is located between the visible and microwave region. 3) Raman lines are weak. 4) When a molecule absorbs infrared radiation then molecule vibrate slower. 5) The differential scanning calorimetry technique is used to measure specific heat with temperature. 6) The basic material for optical fibre is silicon. 	06
Q.2	a) b)	wer the following Explain the working of getter ion pump. Write the advantages of four probe method over two probe method. What is sensor. Discuss different types of sensors. Explain the working of LCR meter.	16
Q.3	Ans a) b)	wer the following Explain in details construction and working of transmission electron microscopy What is shielding. Discuss types of shielding.	16 /.
Q.4	Ans a) b)	w er the following Explain the working of piraniguage. Explain the working of linear variable differential transformer LVDT.	16
Q.5	a)	wer the following Discuss various method used for obtaining low temperature. Explain the working of oil diffusion pump.	16
Q.6	Ans a) b)	wer the following Explain the working of X-ray diffraction method for the analysis of crystal structure. Explain the working of atomic force microscopy with suitable diagram.	16
Q.7		wer the following What is Ruby Laser? Explain the working of Ruby Laser with suitable diagram.	16
	b)	Explain the working principle of differential scanning calorimetry (DSC).	

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Seat No.					Set	Ρ
M.S	P	er - IV) (New) (CE HYSICS (SOLID emiconductor De	STATE	•	Nov-2023	•
	e: Monday, 18 00 PM To 06:0				Max. Marl	ks: 80
Instructio	2) Questic	t five questions. on No.1 and 2 are co t any three from Q. I	•	5		
Q.1 A)	 A CCD i a) char b) only c) only 	ect alternatives. nvolves action ge storage and tran charge transfer storage ge storage and loss	sfer			10
	2) Two vall a) BCS c) RWI	5	b)	GaAs is proposed b BBS NWH	у	
	,	bricated with GaAs e Itra violet Ie	b)	wavelength. ultraviolet infrared		
	4) An overl performaa) CCEc) LAS)		d for improving LED SCR	_	
	5) Photode a) refle c) mod		b)	detects amplify		
	6) The M - a) scho c) ohm		b)	rier. read non – ohmic		
	7) $(\alpha_1 + \alpha_2)$ breakdo a) 100 c) ∞			he SCR devices are 1000 1	at forward	
	a) Pow		b)	f large is invo voltage transfer charge transfer	olved.	

		0)	51101101	ч)		
	10)		ht emission is not possible ir direct band gap indirect band gap	b)	ue to its high mobility doping	
B)	Fill i 1) 2) 3) 4) 5) 6)	Ref Pul The The Swi	aps/State True or False freshing circuit is incorporate lsed laser can deliver very e M-S structure forms e CCD devices are static. e forward characteristic of a itching. T requires 2 V if gate is bias	barri Shoc	er. kley diode is useful for	06
Ans a) b) c) d)	Prog Enha Dyna	gram ance amic	following. hable UJT. ement type MOSFET. c effect in CCD. e and non-radiative transition	ıs.		16
a) b)	Describe the operating principle of photodiode based on PN junctions, pin configuration and multilayer hetrojunction with. band diagrams and IV characteristics. Draw block diagram, doping profile, electric field distribution in p-i-n diode.					10 06
a) b)	char	acte	account of DIAC and TRIAC eristics. di/dt protection.	with	suitable diagrams and IV	10 06
a) b)			e MS structure with band dia trapping in MOSFET.	gram		10 06
a) b)	i) ii) iii)	Spa Que Dela	e GaAs Gun Oscillator mode ace charge accumulation enched domain mode ayed domain mode current flow mechanism in M			10 06
a) b)	quar	ntum	e IV characteristics of solar c n efficiency of solar cell. formance of CCD is improve		erive an expression for	10 06

In a CCD operation the thermal relaxation time is _____ than the charge storage time.

b) much longer

d) much shorter

9)

Q.2

Q.3

Q.4

Q.5

Q.6

Q.7

a) longer

c) shorter

SLR-EU-20

Seat No.	t			Set	Ρ	
	M.Sc. (Semester - IV) (New) (CBCS) Examination: Oct/Nov-2023 PHYSICS (SOLID STATE PHYSICS) Nuclear and Particle Physics (MSC10402)					
			esday, 19-12-2023 1 To 06:00 PM	Max. Marks	: 80	
Instr	uctio	2) Q. Nos. 1 and. 2 are compulsory.) Attempt any three questions from Q. No. 3 to Q. No. 7) Figure to right indicate full marks.			
Q.1	A)	Cho 1)	ose the correct alternative.The binding energy of deuteron isa)13.6 eVb)36 MeVc)2.225 MeVd)13.6MeV		10	
		2)	The range of energy eV is called as epithermal reaa)1eVb)0.025eVc)1KeVd)0.1-1MeV	ction.		
		3)	The simplest two nucleon system exist in nature is ofa)n-nb)n-pc)p-pd)dose not exist			
		4)	the height of potential barrier faced by an alpha particle innucleus isa) 31.2MeVb) 31.2KeVc) 31.2GeVd) 31.2eV	side the		
		5)	The energy equivalent to 1 a m u is a) 931 eV b) 931 KeV c) 931 MeV d) 93 BeV			
		6)	The compound nucleus ha life time is of the order ofa) 10^{-8} Secb) 10^{-11} Secc) 10^{-14} Secd) 10^{-21} Sec	·		
		7)	Unit of cross section is a) Fermi b) barn c) MeV d) nucleon per cm3	3		
		8)	Semi empirical mass formula for the binding energy of nucleon contains a surface correction term this term depends on the number A of the nucleus $A^{1/3}$			
			a) $A^{-1/3}$ b) $A^{2/3}$ c) $A^{1/3}$ d) A			
		9)	The electric quadruple moment is negative, shape of the ra)Oblateb)Prolatec)Sphericald)All of these	nuclei is		
		10)	The Can explain magic number. a) Liquid drop model b) Fermi gas mode c) shell model d) All of these	:I		

	В)	 Fill in the blanks / True or False. 1) Nuclear binding energy usually expressed in units of 2) The exchange particle which holds the quarks together is called 3) In direct reaction incident particle completely have more than Energy per nucleon 4) Cross sectional area of n-p scattering is 4πa²(T/F) 5) In a deuteron, the force between neutron and proton is short range and repulsive (T/F) 6) Nucleons are bosons (T/F) 	06
Q.2	Ans ^r a) b) c) d)	wer in brief. Discuss shape and size, mass and relative abundances of nucleus. Discuss superconductivity model. Write a note on conservation laws. Write a note on cosmic ray.	16
Q.3	Ans a) b)	wer the following. Derive an expression for scattering cross section of two nucleon system and write a note on scattering length. Discuss properties of nuclear forces.	10 06
Q.4	Ans ⁻ a) b)	wer the following. Describe liquid drop model of nucleus point out its usefulness and limitations in understanding the nuclear phenomenon. Explain the energy levels of shell model. How this helps to explain the occurrence of magic numbers? Draw the diagram.	10 06
Q.5	Ans [.] a) b)	wer the following Explain the nuclear reaction kinematics Obtain an expression for Q value discuss the general solution of the Q equation. Comment on compound nuclear disintegration.	10 06
Q.6	a)	wer the following Give the Gell-Mann-Nisijima relation and calculate the charge of baryon family using this relation find out strangeness' and hypercharge of the baryon octet plot the schematic diagram and table.	10
	b)	Discuss quark hypothesis and quantum chromodynamics.	06
Q.7	Ans ⁻ a) b)	wer the following What should be the minimum KE of the electrons to probe the size of $_{20}Ca^{40}$ nucleus. An $_8O^{16}$ nucleus is spherical and has charge radius R and volume according to empirical observation of the charge radii, the volume of the $_{54}Xe^{128}$ nucleus assume to be spherical what is the ratio of volume of Xe to the	10 06
		volume of Oxygen.	

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Seat	
No.	

M.Sc. (Semester - IV) (New) (CBCS) Examination: Oct/Nov-2023 PHYSICS (SOLID STATE PHYSICS) Thin Film Physics and Technology (MSC10403)

Day & Date: Wednesday, 20-12-2023 Time: 03:00 PM To 06:00 PM

Instructions: 1) Question no. 1 and 2 are compulsory.

- 2) Attempt any three guestions from Q. No. 3 to Q. No. 7.
- 3) Figure to right indicate full marks.

Q.1 A) Choose correct alternative.

- Chemical vapour deposition is a method used to obtain which of the 1) following substance?
 - a) Semiconductor

a) Thin film

b) Non conducting polymers c) Crystalline semiconductor d) Conducting compound

d)

- technology is used to get cheap resistor and capacitor? 2)
 - b) Thin and Thick film

Polysilicon

- c) Thick film none of the mentioned d)
- can be doped with P or B to reduce resistivity. 3)
 - a) Silicon dioxide Silicon nitride b)
 - c) Silicon oxy nitride
- metal is not used in metallization. 4)
 - a) Aluminium Chromium b)
 - c) Sodium d) Nickel
- Thin film growth in which small nuclei are formed over the surface of 5) substrate is called .
 - a) nucleation b) growth
 - c) film substrate d)
- PECVD is used for the deposition of thin film. 6)
 - a) metal dielectric b)
 - c) plasma d) conducting
- Spray pyrolysis is an example of 7) phase synthesis.
 - a) solid b) liquid
 - plasma d) c) gas
- can be produced by reacting dichlorosilane and ammonia at 8) temperature between 700°C and 800°C.
 - a) silicon dioxide b) silicon nitride c) silicon dinitride
 - d) polysilicon
- Silicon nitride is often used as an and chemical barrier in 9) manufacturing ICs.
 - a) solid b) insulator
 - c) semiconductor Plasma d)

Set

Max. Marks: 80

	B)	 10) Magnetron sputtering deposition process in which the voltage is delivered across a pressure gas to create high energy plasma. a) high, high b) high, low c) low, low d) low, high Fill in the blanks OR Write True / False	06
	·	 LASER evaporation is the process by which the source material is evaporated by using focused e - beam. True / False Spray pyrolysis is chemical deposition technique. True / False Energies of the order of correspond to physical adsorption. Thin film deposition is the process of creating and depositing thin film coatings onto a substrate material. True / False Polysilicon serves as oxide layer material in MOS devices. True / False In thin film transistor, glass substrate supports a semiconducting film usually of 	
Q.2	a) \ b) [c) [wer the following. What are the factors affecting synthesis of Nanoparticles? Explain dielectric deposition. Explain Polysilicon CVD reaction. Write thin film deposition mechanism in chemical bath deposition.	16
Q.3	a) E	wer the following. Explain with neat diagram of the RF Sputtering Process. Explain polysilicon deposition.	10 06
Q.4	a) E r	wer the following. Explain electrodeposition technique of deposition of thin films with its mechanism. Write a note on Metallization.	10 06
Q.5	a) [\	wer the following. Explain with neat diagram plasma enhanced chemical vapor deposition. What are its advantages and disadvantages? With neat diagram, explain formation stages of thin film.	08 08
Q.6	a) E	wer the following. Explain thin film transistor with its characteristics. Explain dielectric properties of thin film.	10 06
Q.7	a) [wer the following. Describe laser evaporation method for depositing thin film. What are its advantages? Discuss conduction properties in metal thin film.	10 06

Set

Seat No.

M.Sc. (Semester - IV) (New) (CBCS) Examination: Oct/Nov-2023 PHYSICS (SOLID STATE PHYSICS)

Materials Characterization Techniques (MSC10406)

Day & Date: Thursday, 21-12-2023 Time: 03:00 PM To 06:00 PM

1)

Instructions: 1) Q. No. 1 & 2 are compulsory.

- 2) Attempt any three questions from Q. 3 to 7.
- 3) Figures to the right indicate full marks.

Q.1 A) Choose correct alternatives.

- To enhance _____ is crucial in electron microscopy.
 - a) vacuum requirements b) resolution
 - c) electron wavelength d) numerical aperture
- 2) _____ detector is used in SEM to capture the electrons emitted from surface of sample.
 - a) Backscattered electron detector
 - b) Secondary electron detector
 - c) Fluorescence detector
 - d) Transmission electron detector
- 3) What is one solution to the limitation of tunneling current fluctuations in STM?
 - a) Increase the tip-sample distance
 - b) Decrease the tip-sample distance
 - c) Maintain constant tip-sample distance
 - d) Change the electron wavelength
- 4) AFM measures the _____ between the tip and the sample.
 - a) Magnetic force b) Gravitational force
 - c) Mechanical force d) Van der Waals force
- 5) What does Bragg's condition describe in electron diffraction?
 - a) Absorption of electronsc) Interference of electrons
 - b) Refraction of electronsd) Diffraction of electrons
- 6) In XPS, the binding energy of a photoelectron is directly related to the .
 - a) Surface roughness b) Atomic number
 - c) Electron configuration d) Sample thickness
- 7) In AES, the energy of Auger electrons corresponds _
 - a) Atomic number b) Electron configuration
 - c) Core level splitting d) Auger transitions
- 8) Quantum mechanical calculations in NMR are used to predict _____.
 - a) Magnetic field strengthc) Electron configuration
- b) Spin states of nucleid) Chemical bonding
- 9) The hyperfine structure in EPR arises from the interaction between .
 - a) Electrons and protons b) Electrons and electrons

Joules (J)

- c) Nuclei and electrons d) Nuclei and photons
- 10) In NMR spectra, chemical shifts are expressed in units of _
 - a) Hertz (Hz)
- b) Parts per million (ppm)
- c) Tesla (T) d)

Max. Marks: 80

06

16

16

Q.1 B) Write True /False.

- 1) Continuous wave-EPR involves continuously irradiating a sample with microwave radiation while measuring the resulting absorption or emission signals.
- 2) Hyperfine structure in ESR spectroscopy arises from interactions between the electron and nearby nuclear spins.
- 3) Quantum mechanical calculations are essential for predicting the behavior of nuclear spins in NMR spectroscopy.
- 4) Ultra-High Vacuum (UHV) is not necessary in surface characterization to minimize interactions with residual gases.
- 5) STM is limited by its inability to image non-conductive samples.
- 6) Fluorescence microscopy is a technique that uses the property of certain substances to emit light when exposed to specific wavelengths.

Q.2 Answer the following.

- a) Describe the concept of Magic-Angle Spinning (MAS) in the context of NMR.
- b) Explain the concept of a surface in the context of material science.
- c) Discuss advantages and disadvantages of Scanning Electron Microscope (SEM).
- d) Explain the principle of operation of Transmission Electron Microscopy (TEM) and highlight the role of electron beams in imaging.

Q.3 Answer the following.

- **a)** Discuss the instrumentation, experimental conditions, and applications of this EPR technique.
- **b)** Explore the Zeeman interaction in the context of the NMR signal which influences the resonance frequencies observed in NMR spectra.

Q.4 Answer the following.

- a) Explain the challenges and methods involved in achieving quantitative analysis using Auger Electron Spectroscopy and Discuss the factors influences on accuracy of quantitative results.
- **b)** Explore recent advancements in surface analysis techniques. Discuss how these innovations have improved the capabilities and applications of both XPS and AES in material science.

Q.5 Answer the following

- a) Explain principle, instrumentation and working of atomic force microscope.
- b) Draw the schematic diagram of XPS and explain the its working of each part.

Q.6 Answer the following

- a) Describe the lens systems in a Transmission Electron Microscope (TEM) and how these lenses contribute to the magnification and resolution of the images obtained in TEM.
- **b)** Explain how the phase contrast and differential interference contrast techniques enhance the visibility of transparent specimens in optical microscopy.

Q.7 Answer the following

- a) Outline the components of an optical column in electron microscopy.
- b) Explain Raman Spectroscopy with the help of classical and quantum approach

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